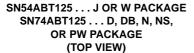
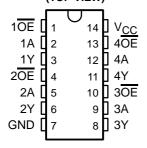
### SN54ABT125, SN74ABT125 QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

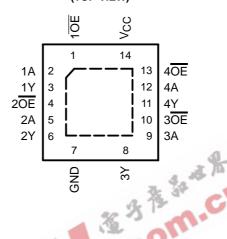
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- Typical V<sub>OLP</sub> (Output Ground Bounce)
   1 V at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C
- High-Drive Outputs (-32-mA I<sub>OH</sub>, 64-mA I<sub>OL</sub>)
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

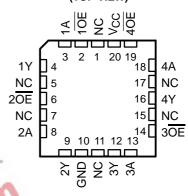




SN74ABT125 ... RGY PACKAGE (TOP VIEW)



SN54ABT125 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

### description/ordering information

The 'ABT125 quadruple bus buffer gates feature independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable (OE) input is high.

These devices are fully specified for hot-insertion applications using I<sub>off</sub> and power-up 3-state. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### ORDERING INFORMATION

TA	PACK	AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	PDIP – N	Tube	SN74ABT125N	SN74ABT125N	
	QFN – RGY	Tape and reel	SN74ABT125RGYR	AB125	
–40°C to 85°C	SOIC - D	Tube	SN74ABT125D	ABT125	
	3010 - 0	Tape and reel	SN74ABT125DR		
	SOP - NS	Tape and reel	SN74ABT125NSR	ABT125	
	SSOP – DB Tape and reel		SN74ABT125DBR	AB125	
	TSSOP – PW Tape and reel		SN74ABT125PWR	AB125	
	CDIP – J	Tube	SNJ54ABT125J	SNJ54ABT125J	
–55°C to 125°C	CFP – W	Tube	SNJ54ABT125W	SNJ54ABT125W	
	LCCC – FK Tube		SNJ54ABT125FK	SNJ54ABT125FK	

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



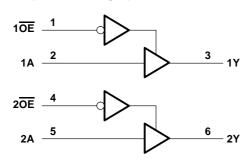
# SN54ABT125, SN74ABT125 **QUADRUPLE BUS BUFFER GATES** WITH 3-STATE OUTPUTS

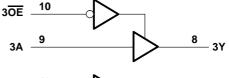
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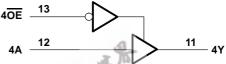
#### **FUNCTION TABLE** (each buffer)

INP	UTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

#### logic diagram (positive logic)







Pin numbers shown are for the D, DB, J, N, NS, PW, RGY, and W packages.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>		–0.5 V to 7 V
		0.5 V to 7 V
Voltage range applied to any out	put in the high or power-off state, Vo	O
Current into any output in the lov	v state, IO: SN54ABT125	96 mA
	SN74ABT125	128 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)		–18 mA
Output clamp current, IOK (VO <	0)	–50 mA
Package thermal impedance, θ <sub>J</sub>	A (see Note 2): D package	86°C/W
	(see Note 2): DB package	96°C/W
	(see Note 2): N package	80°C/W
	(see Note 2): NS package	76°C/W
	(see Note 2): PW package	113°C/W
	(see Note 3): RGY package	47°C/W
Storage temperature range, T <sub>stg</sub>		–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. The package thermal impedance is calculated in accordance with JESD 51-7.
- 3. The package thermal impedance is calculated in accordance with JESD 51-5.



# SN54ABT125, SN74ABT125 **QUADRUPLE BUS BUFFER GATES** WITH 3-STATE OUTPUTS SCBS182I – FEBRUARY 1997 – REVISED NOVEMBER 2002

# recommended operating conditions (see Note 4)

		SN54A	SN54ABT125		SN74ABT125		
		MIN	MAX	MIN	MAX	UNIT	
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V	
VIH	High-level input voltage	2		2		V	
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V	
٧ <sub>I</sub>	Input voltage	0	VCC	0	VCC	V	
ІОН	High-level output current		-24		-32	mA	
loL	Low-level output current		48		64	mA	
Δt/Δν	Input transition rise or fall rate		10		10	ns/V	
Δt/ΔVCC	Power-up ramp rate	200		200		μs/V	
TA	Operating free-air temperature	-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# SN54ABT125, SN74ABT125 **QUADRUPLE BUS BUFFER GATES** WITH 3-STATE OUTPUTS SCBS182I - FEBRUARY 1997 - REVISED NOVEMBER 2002

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		7	A = 25°C	;	SN54A	BT125	SN74ABT125		UNIT	
FARAI	METER	TEST CON	DITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	MAX	MIN	MAX	UNIT	
٧ıK		$V_{CC} = 4.5 \text{ V},$	I <sub>I</sub> = -18 mA			-1.2		-1.2		-1.2	V	
		$V_{CC} = 4.5 \text{ V}, \qquad I_{OH} = -3 \text{ mA}$		2.5			2.5		2.5			
Vон		$V_{CC} = 5 V$ ,	$I_{OH} = -3 \text{ mA}$	3			3		3		v	
۷ОН		V <sub>CC</sub> = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2				V	
		VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2			
VOL		V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA			0.55		0.55			V	
VOL		VCC = 4.3 V	$I_{OL} = 64 \text{ mA}$			0.55*				0.55	V	
$V_{hys}$					100						mV	
lį		$V_{CC} = 0 \text{ to } 5.5 \text{ V}, \qquad V_I = V_{CC} \text{ or GND}$				±1		±1		±1	μΑ	
IOZPU		$V_{CC} = 0 \text{ to } 2.1 \text{ V}, V_{O} = 0.5 \text{ V to } 2.7 \text{ V}, \overline{OE} = X$				±50		±50		±50	μΑ	
IOZPD		$V_{CC} = 2.1 \text{ V to } 0, V_{O} = 0.5 \text{ V to } 2.7 \text{ V}, \overline{OE} = X$				±50		±50		±50	μΑ	
lozh		$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}, \qquad V_{O} = 2.7 \text{ V}, \overline{OE} \ge 2 \text{ V}$				10	-0	10		10	μΑ	
lozL		$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}, \qquad V_{O} = 0.5 \text{ V}, \overline{OE} \ge 2 \text{ V}$				-10		-10		-10	μΑ	
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O \le 4.5 \text{ V}$			±100	4			±100	μΑ	
ICEX		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 5.5 V	Outputs high	**	23	50	Ü,	50		50	μΑ	
1 <sub>0</sub> ‡		$V_{CC} = 5.5 \text{ V},$	V <sub>O</sub> = 2.5 V	-50	-100	-200§	-50	–200§	-50	–200§	mA	
		V <sub>CC</sub> = 5.5 V,	Outputs high		G	250		250		250	μΑ	
ICC		$I_{O} = 0$ ,	Outputs low		24	30		30		30	mA	
		$V_I = V_{CC}$ or GND	Outputs disabled		0.5	250		250		250	μΑ	
	Data	V <sub>CC</sub> = 5.5 V, One input at 3.4 V,	Outputs enabled			1.5		1.5		1.5		
$\Delta I_{CC}^{\P}$	inputs	Other inputs at VCC or GND	Outputs disabled			0.05		0.05		0.05	mA	
	Control inputs	V <sub>CC</sub> = 5.5 V, One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND				1.5		1.5		1.5		
Ci		V <sub>I</sub> = 2.5 V or 0.5 V			3						pF	
Co		V <sub>O</sub> = 2.5 V or 0.5 V			7						pF	

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter does not apply.



<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ .

<sup>‡</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

<sup>§</sup> This limit may vary among suppliers.

<sup>¶</sup> This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.

# SN54ABT125, SN74ABT125 **QUADRUPLE BUS BUFFER GATES** WITH 3-STATE OUTPUTS SCBS182I – FEBRUARY 1997 – REVISED NOVEMBER 2002

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>(</sub>	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C SN54ABT125 SN			SN74A	BT125	UNIT	
	(INFOT)	(001F01)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	unit ns ns
t <sub>PLH</sub> †	А	<b>~</b>	1	3.2	4.6	1	6	1	4.9	no
t <sub>PHL</sub> †		ľ	1	2.5	4.6	1	6.2	1	4.9	115
t <sub>PZH</sub> †	<del></del>		1	3.6	5	1	6	1	5.9	no
t <sub>PZL</sub> †	ŌĒ	Ĭ	1	2.5	6.2	1	7.5	1	6.8	110
<sup>t</sup> PHZ	<del></del>	<del>or</del> v	1	3.8	5.4	1	6.3	1	6.2	nc
t <sub>PLZ</sub> †	OE	r	1	3.3	5.3	1	6.5	1	6.2	115

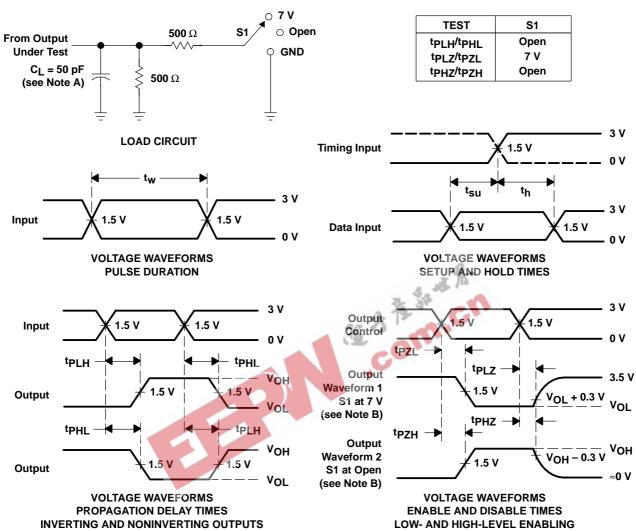
<sup>†</sup> This limit may vary among suppliers.



# SN54ABT125, SN74ABT125 **QUADRUPLE BUS BUFFER GATES** WITH 3-STATE OUTPUTS

SCBS182I – FEBRUARY 1997 – REVISED NOVEMBER 2002

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \ \Omega$ ,  $t_f \leq 2.5 \ ns$ .
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





#### PACKAGE OPTION ADDENDUM

28-Feb-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp (3)
5962-9676801Q2A	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
5962-9676801QCA	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
5962-9676801QDA	ACTIVE	CFP	W	14	1	None	Call TI	Level-NC-NC-NC
SN74ABT125D	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
SN74ABT125DBLE	OBSOLETE	SSOP	DB	14		None	Call TI	Call TI
SN74ABT125DBR	ACTIVE	SSOP	DB	14	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
SN74ABT125DR	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
SN74ABT125N	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN74ABT125NSR	ACTIVE	SO	NS	14	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
SN74ABT125PW	ACTIVE	TSSOP	PW	14	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
SN74ABT125PWLE	OBSOLETE	TSSOP	PW	14	272	None	Call TI	Call TI
SN74ABT125PWR	ACTIVE	TSSOP	PW	14	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
SN74ABT125RGYR	ACTIVE	QFN	RGY	14	1000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR
SNJ54ABT125FK	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
SNJ54ABT125J	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
SNJ54ABT125W	ACTIVE	CFP	W	14	1	None	Call TI	Level-NC-NC-NC

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

None: Not yet available Lead (Pb-Free).

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<sup>(2)</sup> Eco Plan - May not be currently available - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.



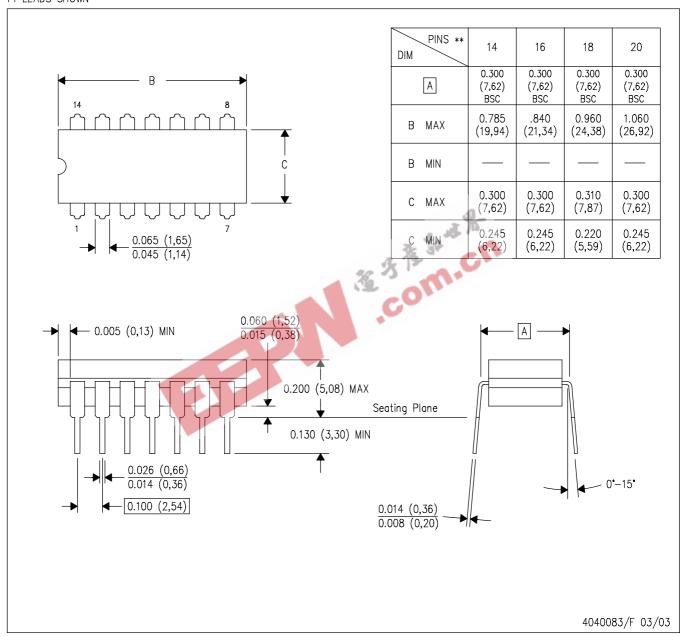
# **PACKAGE OPTION ADDENDUM**

28-Feb-2005

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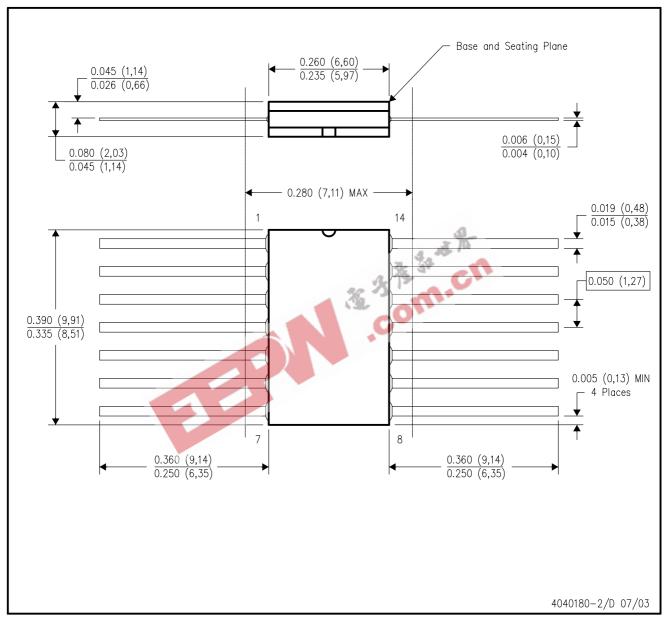
14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- $E. \quad \text{Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.} \\$

# W (R-GDFP-F14)

# CERAMIC DUAL FLATPACK



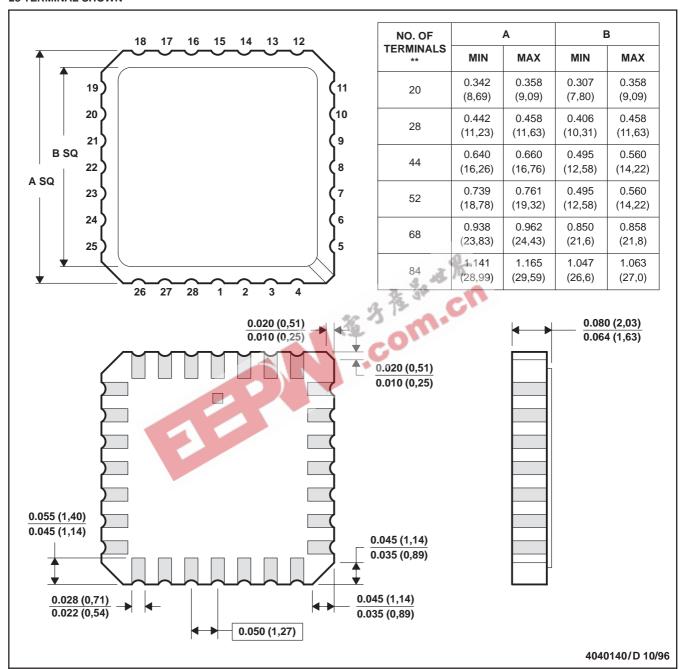
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14 and JEDEC MO-092AB



#### FK (S-CQCC-N\*\*)

#### LEADLESS CERAMIC CHIP CARRIER

#### **28 TERMINAL SHOWN**



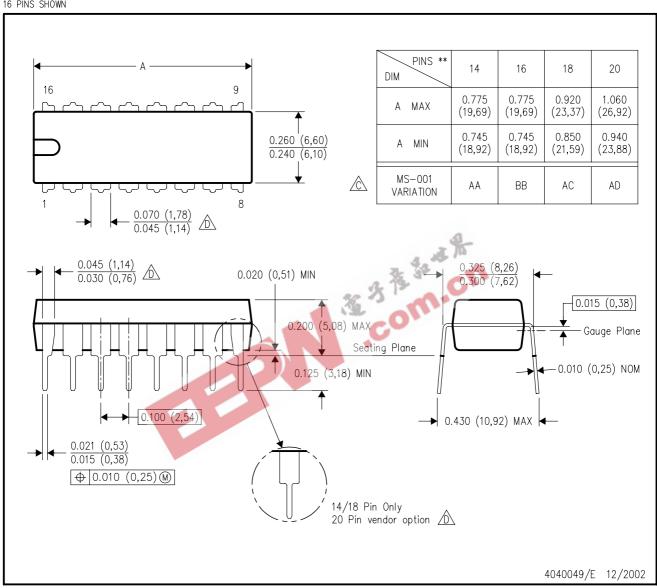
- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. This package can be hermetically sealed with a metal lid.
  - D. The terminals are gold plated.
  - E. Falls within JEDEC MS-004



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

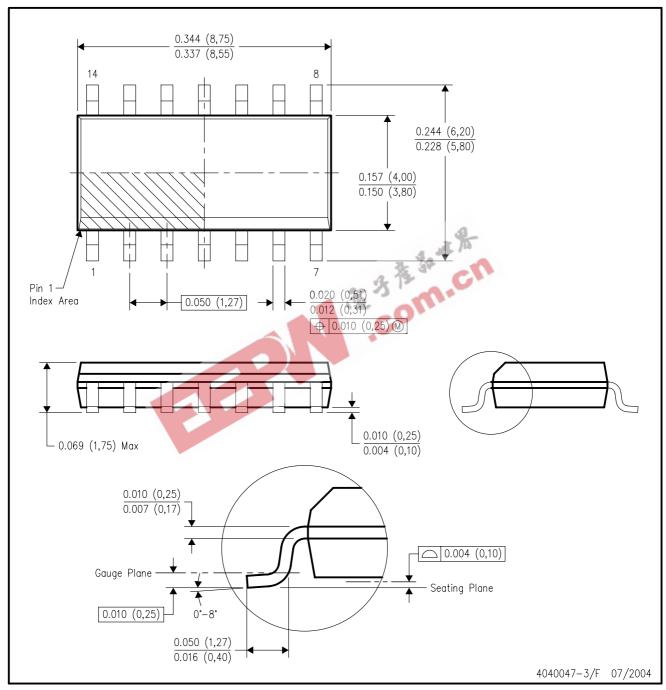
16 PINS SHOWN



- All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.

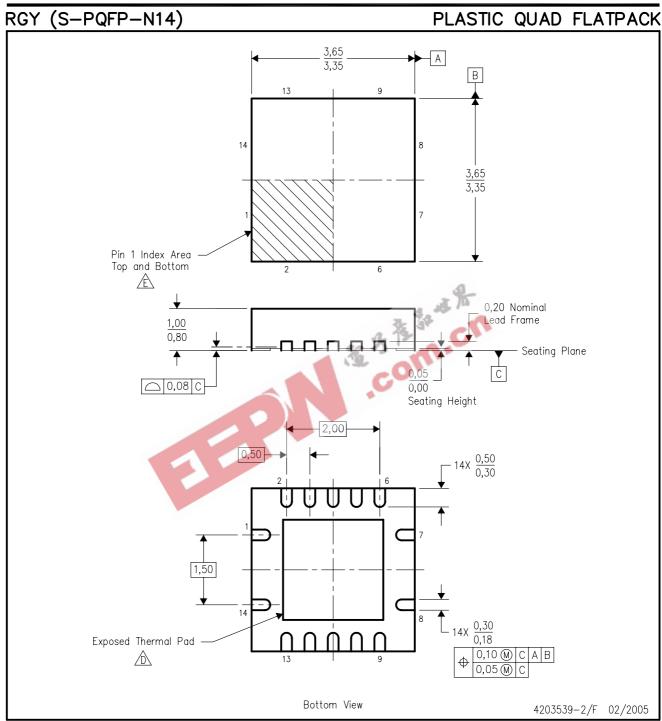
# D (R-PDSO-G14)

# PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BA.

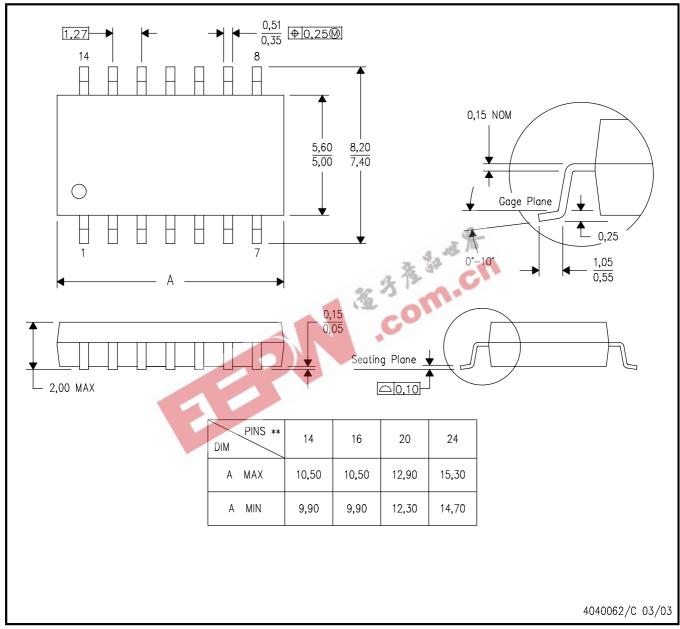


### **MECHANICAL DATA**

### NS (R-PDSO-G\*\*)

### 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



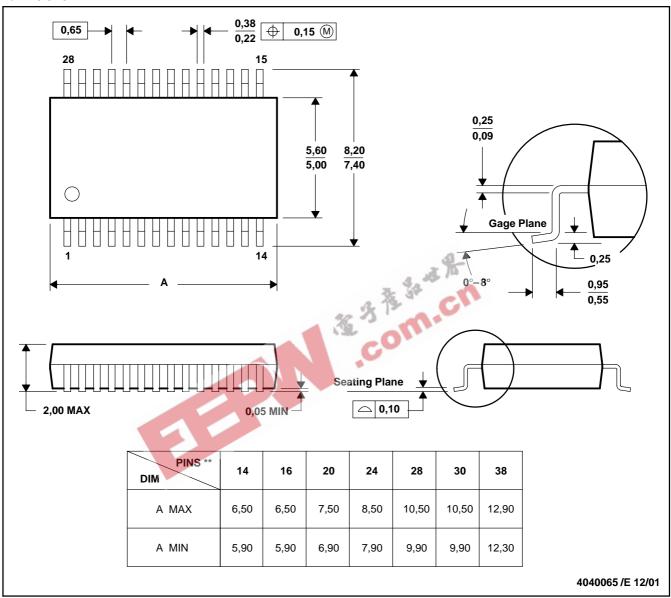
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### DB (R-PDSO-G\*\*)

#### **PLASTIC SMALL-OUTLINE**

#### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

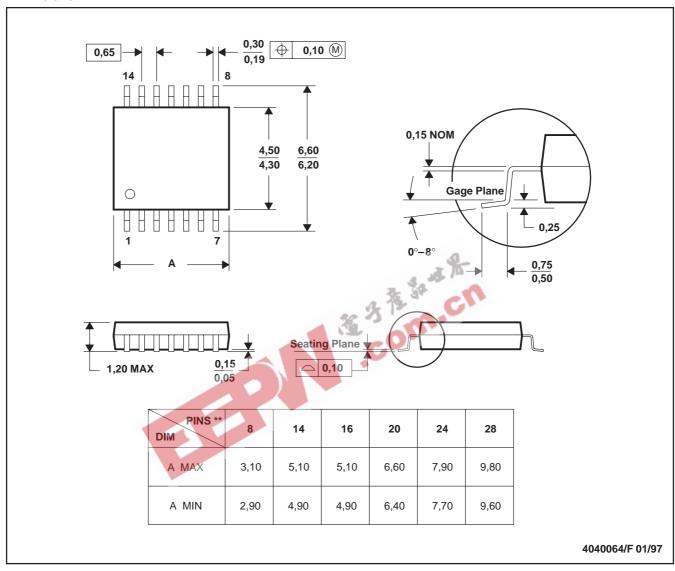
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

### PW (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

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